## NSN 5961-01-152-0162

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**Inclosure Material:** Metal **Overall Length:** 1.573 inches **Terminal Length:** Between 0.360 inches and 0.500 inches **Overall Height:** Between 0.250 inches and 0.340 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 collector to emitter voltage/static/base open and 600.0 collector to emitter voltage, dc with specified circuit between base and emitter and 9.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Shelf Life:

1 case and 2 pin **Specification Data:** 

**Terminal Type And Quantity:** 

81349-mil-s-19500/525 government specification

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Demilitarization:

No

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